

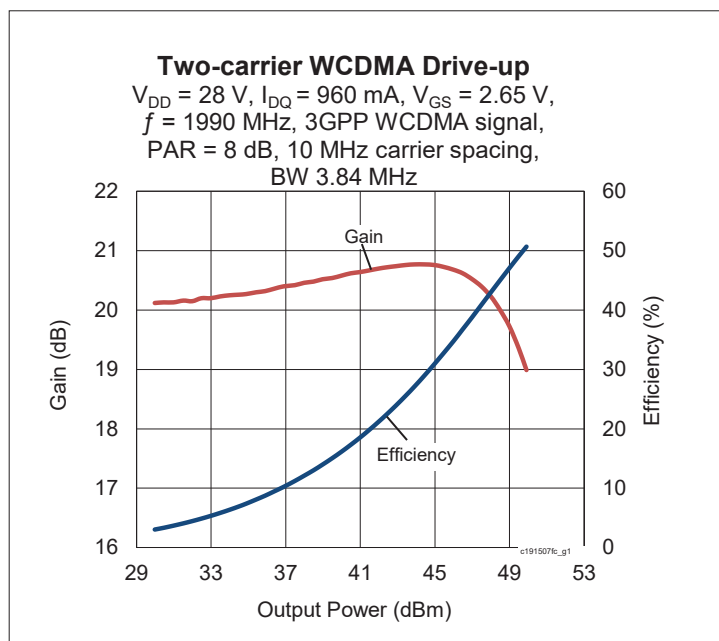
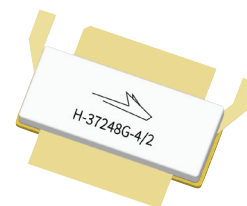
PXFC191507FC

Thermally-Enhanced High Power RF LDMOS FET 150 W, 28 V, 1805 – 1990 MHz

Description

The PXFC191507FC is a 150-watt LDMOS FET intended for use in multi-standard cellular power amplifier applications in the 1805 to 1990 MHz frequency band. Features include input and output matching, high gain and thermally-enhanced package with earless flanges. Manufactured with Wolfspeed's advanced LDMOS process, this device provides excellent thermal performance and superior reliability.

PXFC191507FC
Package H-37248G-4/2



Features

- Broadband internal input and output matching
- Typical Pulsed CW performance, 1990 MHz, 28 V, 10 μs pulse width, 10% duty cycle, class AB test
 - Output power at P_{1dB} = 140 W
 - Efficiency = 54%
 - Gain = 19.5 dB
- Typical single-carrier WCDMA performance, 1990 MHz, 28 V, 10 dB PAR @ 0.01% CCDF, Test Model 1 with 16DPCH
 - Output power = 32 W avg
 - Efficiency = 34%
 - Gain = 20 dB
 - ACPR = -31 dBc @ 5 MHz
- Capable of handling 10:1 VSWR @ 28 V, 150 W (CW) output power
- Integrated ESD protection : Human Body Model, Class 1C (per JESD22-A114)
- Low thermal resistance
- Pb-free and RoHS compliant

RF Characteristics

Two-carrier WCDMA Specifications (tested in Wolfspeed production test fixture)

$V_{DD} = 28\text{ V}$, $I_{DQ} = 960\text{ mA}$, $P_{OUT} = 32\text{ W avg}$, $f_1 = 1980\text{ MHz}$, $f_2 = 1990\text{ MHz}$, 3GPP signal, channel bandwidth = 3.84 MHz, peak/average = 8 dB @ 0.01% CCDF

Characteristic	Symbol	Min	Typ	Max	Unit
Gain	G_{ps}	19	20.5	—	dB
Drain Efficiency	η_D	29	31	—	%
Intermodulation Distortion	IMD	—	-33	-31	dBc

All published data at $T_{CASE} = 25^\circ\text{C}$ unless otherwise indicated

ESD: Electrostatic discharge sensitive device—observe handling precautions!



DC Characteristics (each side)

Characteristic	Conditions	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_{DS} = 10\text{ mA}$	$V_{(BR)DSS}$	65	—	—	V
Drain Leakage Current	$V_{DS} = 28\text{ V}, V_{GS} = 0\text{ V}$	I_{DSS}	—	0.05	1	μA
	$V_{DS} = 63\text{ V}, V_{GS} = 0\text{ V}$	I_{DSS}	—	—	10	μA
On-State Resistance	$V_{GS} = 10\text{ V}, V_{DS} = 0.1\text{ V}$	$R_{DS(on)}$	—	0.05	—	Ω
Operating Gate Voltage	$V_{DS} = 26\text{ V}, I_{DQ} = 960\text{ mA}$	V_{GS}	2.3	2.6	2.9	V
Gate Leakage Current	$V_{GS} = 10\text{ V}, V_{DS} = 0\text{ V}$	I_{GSS}	—	—	1	μA

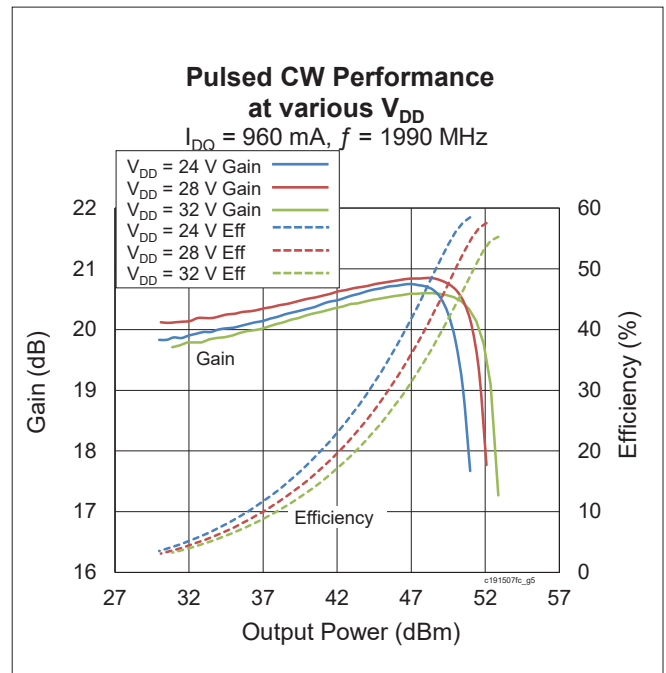
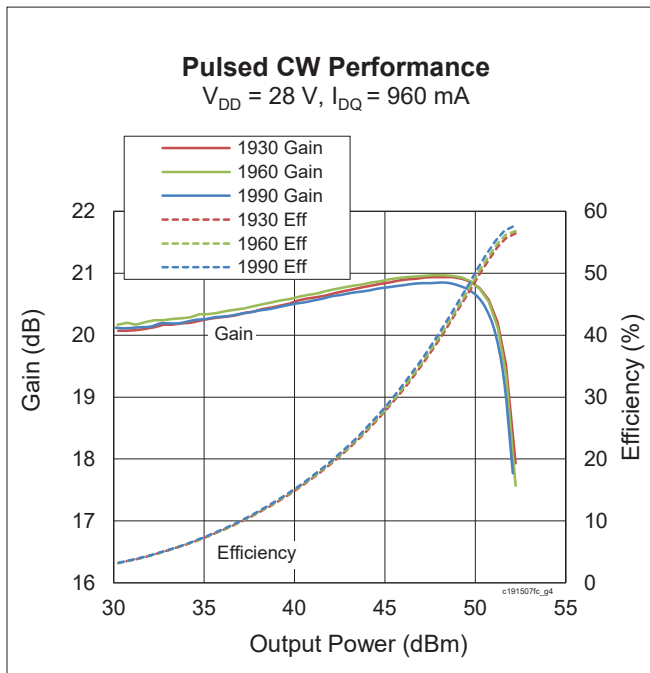
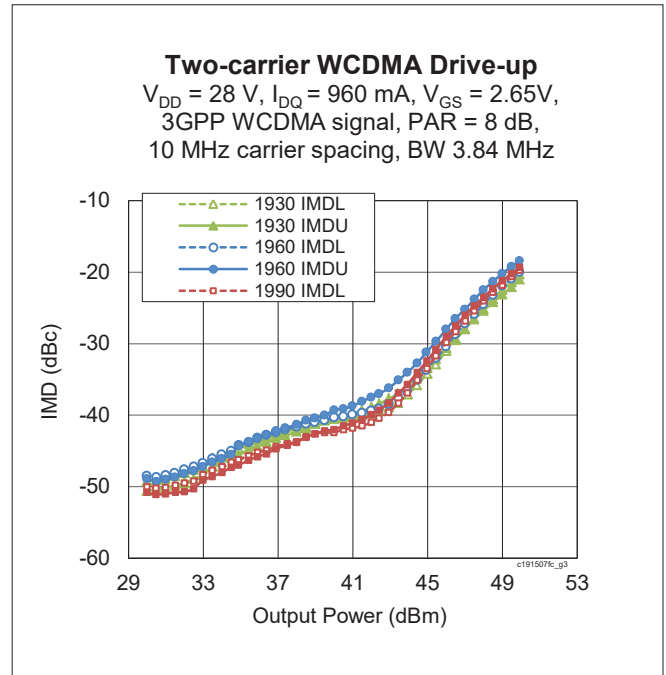
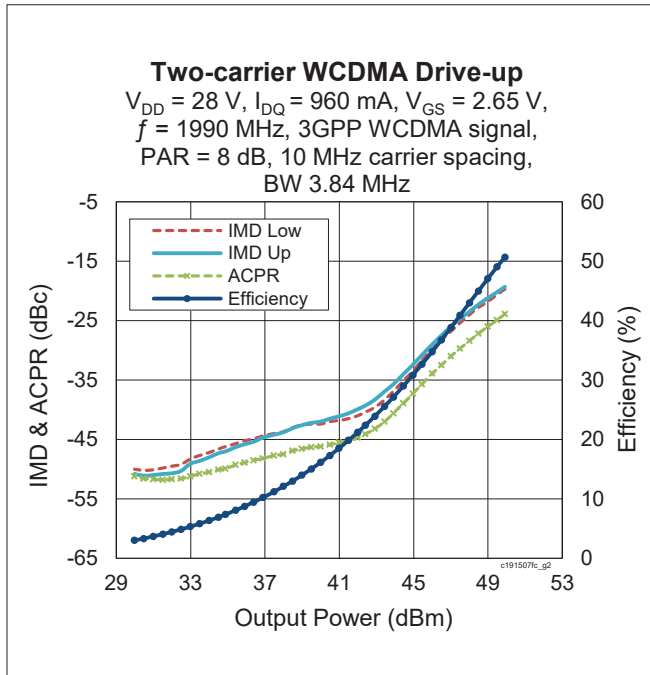
Maximum Ratings

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	65	V
Gate-Source Voltage	V_{GS}	-6 to +10	V
Operating Voltage	V_{DD}	0 to +32	V
Junction Temperature	T_J	225	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-65 to +150	$^{\circ}\text{C}$
Thermal Resistance ($T_{CASE} = 70^{\circ}\text{C}, 140\text{ W CW}$)	$R_{\theta JC}$	0.43	$^{\circ}\text{C/W}$

Ordering Information

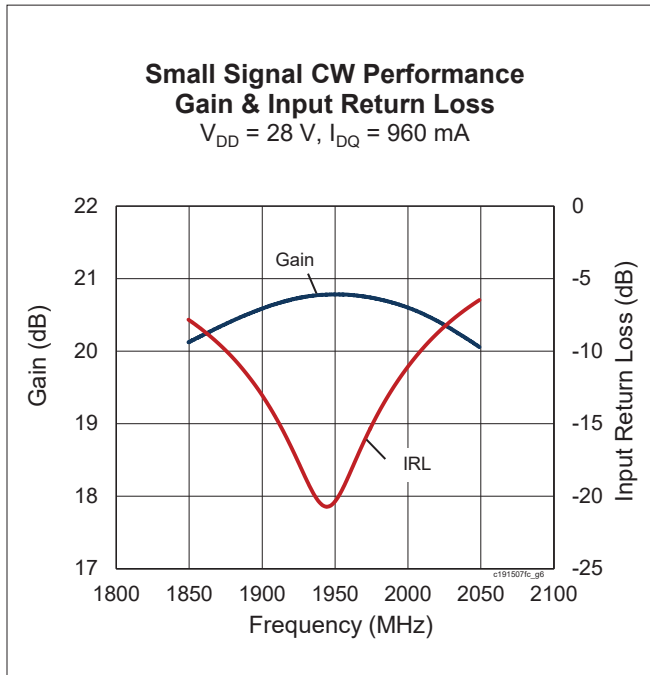
Type and Version	Order Code	Package Description	Shipping
PXFC191507FC V1 R0	PXFC191507FC-V1-R0	H-37248G-4/2, earless flange	Tape & Reel, 50 pcs
PXFC191507FC V1 R250	PXFC191507FC-V1-R250	H-37248G-4/2, earless flange	Tape & Reel, 250 pcs

Typical Performance (data taken in a production test fixture)

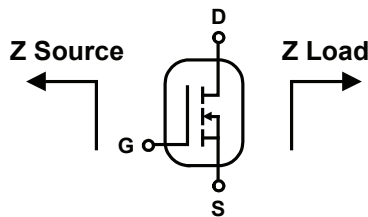




Typical Performance (cont.)



Broadband Circuit Impedance



Freq [MHz]	Z Source Ω		Z Load Ω	
	R	jX	R	jX
1930	1.34	-4.30	1.55	-3.14
1960	1.28	-4.15	1.54	-2.99
1990	1.25	-4.04	1.52	-2.86

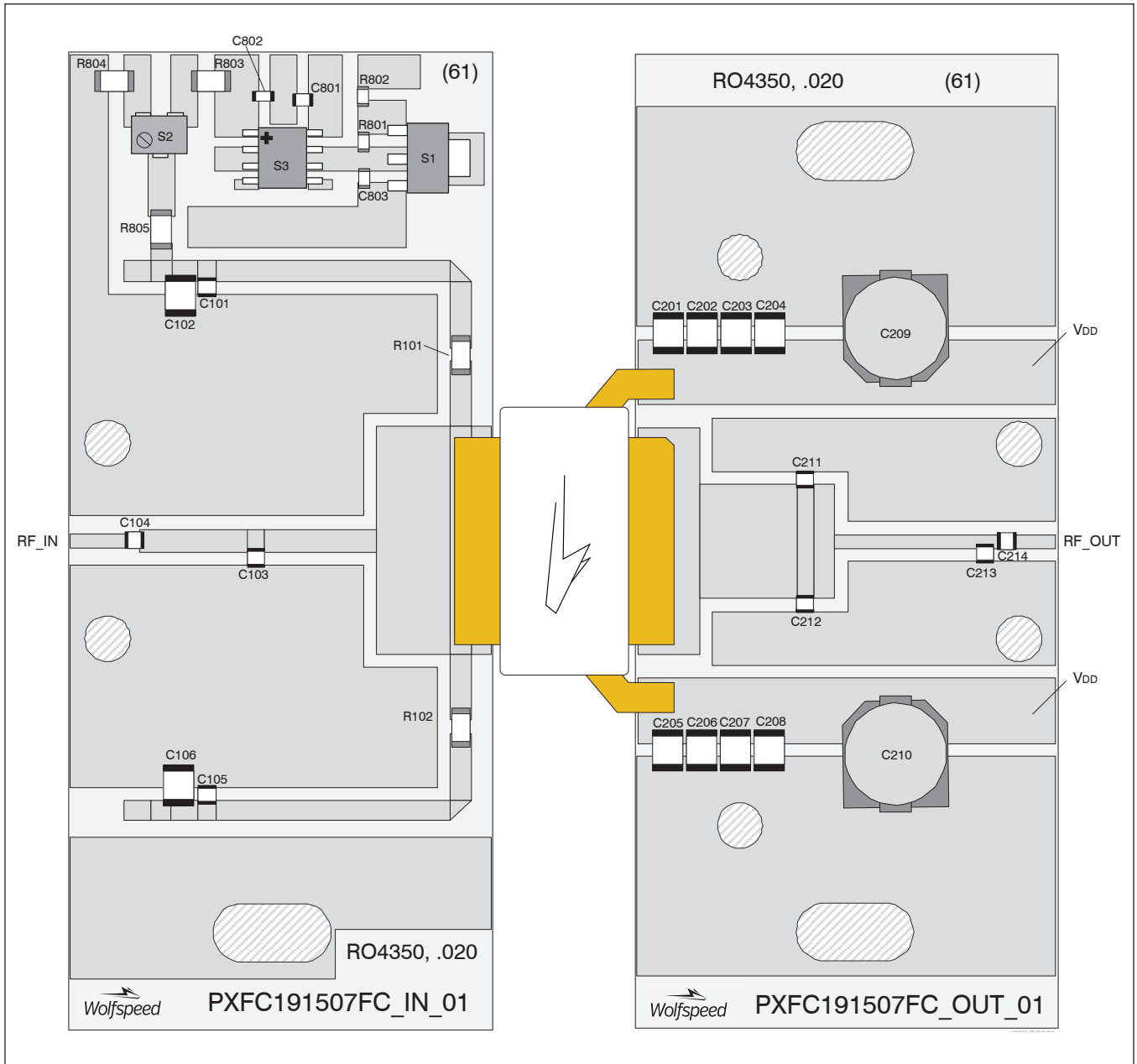
Load Pull Performance

Main Side Load Pull Performance – Pulsed CW signal: 100 μs , 10% duty cycle, $V_{DD} = 28\text{ V}$, $I_{DQ} = 960\text{ mA}$

Freq [MHz]	Zs [Ω]	P _{1dB}									
		Max Output Power					Max PAE				
		ZI [Ω]	Gain [dB]	P _{OUT} [dBm]	P _{OUT} [W]	PAE [%]	ZI [Ω]	Gain [dB]	P _{OUT} [dBm]	P _{OUT} [W]	PAE [%]
1805	1.00 - j3.39	1.36 - j2.81	18.2	52.30	170	58.1	2.82 - j2.46	20.4	50.40	110	65.7
1880	1.38 - j3.80	1.26 - j3.35	17.8	52.10	164	54.7	2.48 - j2.33	20.2	50.50	112	64.8
1930	1.88 - j4.65	1.14 - j3.38	17.6	52.10	162	52.1	2.25 - j2.06	20.1	50.20	104	63.7
1990	2.85 - j4.62	1.31 - j3.40	18.4	52.00	157	56.4	1.81 - j2.40	19.9	50.60	116	62.8



Reference Circuit , 1930 – 1990 MHz



Reference circuit assembly diagram (not to scale)

Reference Circuit (cont.)**Reference Circuit Assembly**

DUT	PXFC191507FC V1
Test Fixture Part No.	LTN/PXFC191507FC V1
PCB	Rogers 4350, 0.508 mm [0.020"] thick, 2 oz. copper, $\epsilon_r = 3.66$, $f = 1930 - 1990$ MHz
Find Gerber files for this test fixture on the Wolfspeed Web site at www.wolfspeed.com/RF	

Components Information

Component	Description	Suggested Manufacturer	P/N
Input			
C101, C104, C105,	Capacitor, 33 pF	ATC	ATC800A330JT250
C102, C106	Capacitor, 10 μ F	Taiyo Yuden	UMK325C7106MM-T
C103	Capacitor, 1.0 pF	ATC	ATC800A1R0BT250
C801, C802, C803	Capacitor, 1000 pF	Panasonic Electronic Components	ECJ-1VB1H102K
R101, R102, R805	Capacitor, 10 ohms	Panasonic Electronic Components	ERJ-8GEYJ100V
R801	Resistor, 1200 Ohm	Panasonic Electronic Components	ERJ-3GEYJ122V
R802	Resistor, 1300 Ohm	Panasonic Electronic Components	ERJ-3GEYJ132V
R803, R804	Capacitor, 100 ohms	Panasonic Electronic Components	ERJ-8GEYJ101V
S1	Transistor	Infineon Technologies	BCP56
S2	Potentiometer, 2k Ω	Bourns Inc.	3224W-1-202E
S3	Voltage Regulator	Texas Instruments	LM7805
Output			
C201, C202, C203, C204, C205, C206, C207, C208	Capacitor, 10 μ F	Taiyo Yuden	UMK325C7106MM-T
C209, C210	Capacitor, 220 μ F	Panasonic Electronic Components	EEE-FP1V221AP
C211, C212, C213	Capacitor, 0.3 pF	ATC	ATC800A0R3BT250
C214	Capacitor, 33 pF	ATC	ATC800A330JT250

Package Outline Specifications

